



Docket No: 740756-1638

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Is re PATENT application of )  
Hisashi OHTANI et al. )  
Serial No. 08/807,737 ) Art Unit: 2829  
Filed: February 27, 1997 ) Examiner: Evan Pert  
For: METHOD FOR MANUFACTURING ) Confirmation No. 5408  
SEMICONDUCTOR DEVICE )

CORRECTION TO PRIOR INFORMATION DISCLOSURE STATEMENT

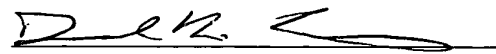
Honorable Commissioner for Patents  
Washington, D.C. 20231

Sir:

Applicants have identified two typographical errors in Form PTO-1449 that was filed in the United States Patent and Trademark Office with an Information Disclosure Statement (IDS) on August 23, 2003. In particular, the date of the publication of Yunosuke KAWAZU et al. should be 12/1999, it was incorrectly noted as 10/20/1999. In addition, the page number for the publication of T.I. Kamins should be (pp. 817-824) it was incorrectly noted as (pp. 817-828). In order to correct these errors, Applicants enclose a new Form PTO-1449 to correctly cite the previous errors. Applicants respectfully request the Examiner initial and date the enclosed Form PTO-1449 to indicate consideration of these references and mark through the incorrect entries provided on the Form PTO-1449 filed on August 23, 2003. The references were previously submitted and therefore, Applicants have not attached additional copies of the references.

The Commissioner is hereby authorized to charge fees under 37 C.F.R. §§1.16, 1.17, 1.20(a), 1.20(b), 1.20(c), and 1.20(d) which may be required now or hereafter, or credit any overpayment to Deposit Account No. 19-2380 (740756-1638).

Respectfully submitted,  
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Substitute for form 1449A/PTO				<b>Complete if Known</b>	
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <i>(use as many sheets as necessary)</i>				Application Number	08/807,737
				Filing Date	February 27, 1997
				First Named Inventor	Hisashi Ohtani et al.
				Art Unit	2829
				Examiner Name	Evan T. Pert
Sheet	1	of	1	Attorney Docket Number	740756-1638

U.S. PATENT DOCUMENTS					
Examiner Initials <sup>*</sup>	Cite No. <sup>1</sup>	U.S. Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code <sup>2</sup> (if known)			
		US-			
		US-			
		US-			
		US-			
		US-			

FOREIGN PATENT DOCUMENTS						
Examiner Initials <sup>*</sup>	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>2</sup> (if known)				

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials <sup>*</sup>	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
		T.I. Kamins "Design Properties of Polycrystalline Silicon" Sensors and Actuators, A21-A23 (1990) pp. 817-824	
		Yunosuke KAWAZU et al. "Low-Temperature Crystallization of Hydrogenated Amorphous Silicon Induced by Nickel Silicide Formation" Institute of Applied Physics, University of Tsukuba, pp.2698-2704 (12/1990)	

Examiner Signature	Date Considered
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See Kinds Codes of USPTO Patent Documents at [www.uspto.gov](http://www.uspto.gov) or MPEP 901.04. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.

<sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> Applicant is to place a check mark here if English language Translation is attached.